Search Notes

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	448	(257/528).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/26 20:40
L2	1297	(257/536).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/26 20:42
L3	437	(257/537).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/26 20:42
S1	20	(("6,188,615") or ("6,128,239") or ("6,185,143") or ("6,504,750") or ("6,314,014") or ("5,982,659") or ("6,542,397") or ("6,458,676") or ("6,417,043") or ("6,380,597")). PN. or (2003/0043616).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/26 20:40
S2	9476	resistance and non-volatile adj memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/21 15:25
S3	2962	resistance and non-volatile adj memory and rows and columns	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/21 15:25
S4	593	resistance adj value and non-volatile adj memory and rows and columns	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/21 15:34
S5	94	resistance adj value same logic and non-volatile adj memory and rows and columns	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/21 15:26
S6	6	resistance adj value with bit same logic and non-volatile adj memory and rows and columns	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37

S7	11	Anderson-Daryl.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S8	111	Van-Brocklin-Andrew-L.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S9	78	Fricke-Peter.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S10	20	resistance adj value same shape and non-volatile adj memory and rows and columns	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/21 15:36
S11	2	resistance adj value same geometric with shape and non-volatile adj memory and rows and columns	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/01/21 15:35
S12	46	"5748519"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 15:09
S13	0	"5748519" and mutiple adj logic$2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 15:09
S14	0	"5748519" and mutiple with logic$2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 15:10
S15	0	"5748519" and multiple with logic$2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 15:10
S16	17	"5748519" and logic$2 with bit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 17:11

S17	0	"6490190" and logic$2 with bit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 16:02
S18	10	"6490190"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 16:02
S19	547	phase adj change and resistive and non-volatile	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 17:11
S20	52	phase adj change and resistive and non-volatile adj memory with cell	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 17:23
S21	16	phase adj change and resistive and non-volatile adj memory with cell and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 17:37
S22	24	phase adj change and resistive and kuroda	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S23	0	pervoskite and resistive and memory and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 17:39
S24	151	perovskite and resistive and memory and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 17:40
S25	13	perovskite and resistive and non-volatile with memory and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S27	2	multi-resistive and non-volatile with memory and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37

S28	138	perovskite and resistive and non-volatile with memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 17:43
S29	1	"20030043616".PN.	US-PGPUB	OR	ON	2005/06/29 17:49
S30	1	"6504750".PN.	USPAT; USOCR	OR	ON	2005/06/29 17:49
S31	1	"6314014".PN.	USPAT; USOCR	OR	ON	2005/06/29 17:49
S32	1	"20030043616".PN.	US-PGPUB	OR	ON	2005/06/29 17:49
S33	151	Van-Brocklin-Andrew-L.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S34	11	Anderson-Daryl.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S35	86	Fricke-Peter.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S36	6	resistance adj value with bit same logic and non-volatile adj memory and rows and columns	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S37	24	phase adj change and resistive and kuroda	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S38	2	multi-resistive and non-volatile with memory and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37
S39	31	perovskite and resistive and non-volatile with memory and matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 20:37